

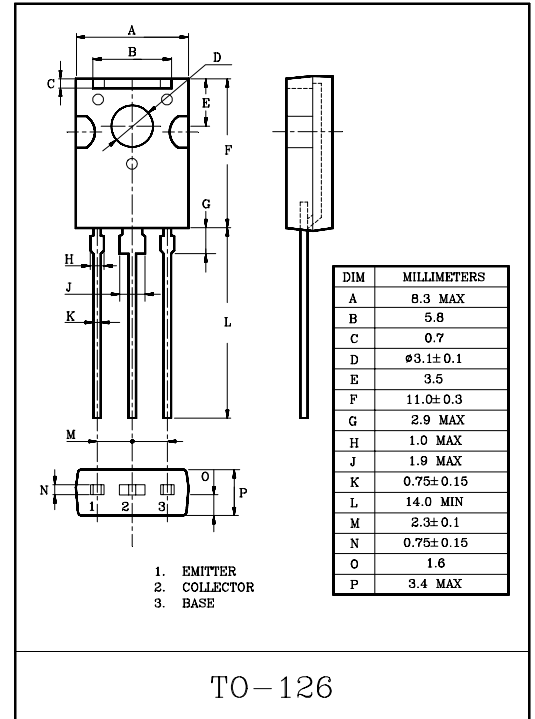
HIGH VOLTAGE APPLICATION.

FEATURES

- High Transition Frequency : $f_T=100\text{MHz(Typ.)}$.
- Complementary to KTC2800.

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	-160	V
Collector-Emitter Voltage	V_{CEO}	-160	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-1.5	A
Base Current	I_B	1.0	A
Collector Power Dissipation	$T_a=25^\circ\text{C}$	1.5	W
	$T_c=25^\circ\text{C}$	10	
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55~150	$^\circ\text{C}$



ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=-160\text{V}, I_E=0$	-	-	-1.0	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=-5\text{V}, I_C=0$	-	-	-1.0	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=-10\text{mA}, I_B=0$	-160	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=-1\text{mA}, I_C=0$	-5.0	-	-	V
DC Current Gain	$h_{FE}(\text{Note})$	$V_{CE}=-5\text{V}, I_C=-100\text{mA}$	70	-	240	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-500\text{mA}, I_B=-50\text{mA}$	-	-	-1.5	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=-5\text{V}, I_C=-500\text{mA}$	-	-	-1.0	V
Transition Frequency	f_T	$V_{CE}=-10\text{V}, I_C=-100\text{mA}$	-	100	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=-10\text{V}, I_E=0, f=1\text{MHz}$	-	30	-	pF

Note : h_{FE} Classification 0:70~140, Y:120~240